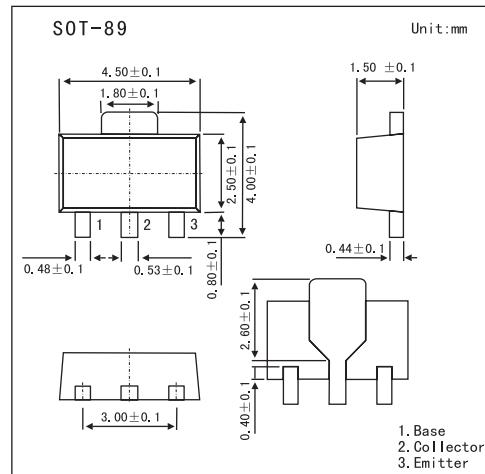


# 2SB1589

## ■ Features

- Low collector to emitter saturation voltage VCE(sat).
- Large collector power dissipation PC.
- Mini Power type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.



## ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	-10	V
Collector-emitter voltage	V <sub>CEO</sub>	-10	V
Emitter-base voltage	V <sub>EBO</sub>	-7	V
Peak collector current	I <sub>CP</sub>	-2	A
Collector current	I <sub>C</sub>	-1.5	A
Collector power dissipation	P <sub>C</sub>	1	W
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

## ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector cutoff current	I <sub>CBO</sub>	V <sub>CB</sub> = -7 V, I <sub>E</sub> = 0			-1	μA
Collector-base voltage	V <sub>CBO</sub>	I <sub>C</sub> = -10 μA, I <sub>E</sub> = 0	-10			V
Collector-emitter voltage	V <sub>CEO</sub>	I <sub>C</sub> = -1 mA, I <sub>B</sub> = 0	-10			V
Emitter-base voltage	V <sub>EBO</sub>	I <sub>E</sub> = -10 μA, I <sub>C</sub> = 0	-7			V
Forward current transfer ratio	h <sub>FE</sub>	V <sub>CE</sub> = -1 V, I <sub>C</sub> = -400 mA	200		700	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = -1A, I <sub>B</sub> = - 25 mA		-0.24	-0.35	V
Transition frequency	f <sub>T</sub>	V <sub>CB</sub> = -6 V, I <sub>E</sub> = 50 mA, f = 200 MHz		190		MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10V, I <sub>E</sub> = 0, f = 1 MHz		6.5		pF
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = -500 mA			1.3	V

## ■ Marking

Marking	1U
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